GUJARAT TECHNOLOGICAL UNIVERSITY BE - SEMESTER-V EXAMINATION – WINTER 2015

Su	bjec	t Code: 152401 Date:15/12/2015	
Su	bjec	t Name: Power Electronics Devices & Components	
		10:30am to 1:00pmTotal Marks: 70	
Ins	truction1	ons: . Attempt all questions.	
	2 3	. Make suitable assumptions wherever necessary.	
Q.1	(a)	Explain the construction and working of Power Diode along with VI characteristics.	07
	(b)	Explain UJT as a relaxation oscillator.	07
Q.2	(a)	Draw the block diagram of Power Electronics System. Explain in brief the concept of Power & Energy.	07
	(b)	Draw the practical switch characteristics. And explain the concept of Safe Operating Area (SOA).	07
		OR	
	(b)	Discuss the requirement of Electrical Power Conversion and explain the concept of Power Processing.	07
Q.3	(a) (b)	Explain Fast Recovery Diode. Give its applications. Explain the working principle and structure of Power BJT.	07 07
		OR	
Q.3	(a)	Explain P-N junction diode along with its I-V characteristics.	06
χ.υ	(b)	Draw the input, output and switching characteristics of BJT	08
Q.4	(a) (b)	Explain the two transistor model of thyristor. Explain the turn-on methods of thyristor.	07 07
	(0)	Explain the turn-on methods of thyristor.	07
		OR	
Q.4	(a) (b)	Explain the over voltage and over current protection circuit for thyristor. What do you mean by commutation of thyristor? List different thyristor commutation techniques and define Holding & Latching current.	07 07
Q.5	(a) (b)	Explain the construction and working of Power MOSFET. Explain the construction and working of IGBT.	07 07
		OR	
Q.5	(a) (b)	Draw the symbol & structure of TRIAC and explain its working. Discuss the necessity of cooling in power switches. Also discuss in brief various heat sinks and mountings used for various power switches.	07 07
